

# **HipPerFET™ Module**

VMO 580-02F

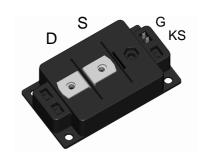
 $V_{DSS} = 200 V$ 

 $I_{D25} = 580 \text{ A}$ 

 $R_{DS(on)} = 3.8 \text{ m}\Omega$ 

## N-Channel Enhancement Mode





# **Preliminary Data**

MOSFET				
Symbol	Conditions	Maximum Rat	Maximum Ratings	
V <sub>DSS</sub>	T <sub>VJ</sub> = 25°C to 150°C	200	V	
V <sub>GS</sub>		±20	V	
I <sub>D25</sub> I <sub>D80</sub>	$T_{c} = 25$ °C $T_{c} = 80$ °C	580 430	A A	
   <sub>F25</sub>   <sub>F80</sub>	(diode) $T_C = 25^{\circ}C$ (diode) $T_C = 80^{\circ}C$	580 430	A A	

Symbol	Conditions	Characteristic Values
		$(T_{VJ} = 25^{\circ}C, \text{ unless otherwise specified})$
		min. ∣ tvn. ∣ max.

		mın.	typ.	max.	
R <sub>DSon</sub>	V <sub>GS</sub> = 10 V; I <sub>D</sub> = I <sub>D80</sub>		3.2	3.8	mΩ
$V_{\rm GSth}$	$V_{DS} = 20 \text{ V}; I_{D} = 50 \text{ mA}$	2		4	V
I <sub>DSS</sub>	$V_{DS} = 0.8 \bullet V_{DSS}$ ; $V_{GS} = 0 \text{ V}$ ; $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		3	2.6	mA mA
I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$			1	μΑ
Q <sub>g</sub> Q <sub>gs</sub> Q <sub>gd</sub>	$ V_{GS} = 10 \text{ V}; V_{DS} = 0.5 \bullet V_{DSS}; I_{D} = I_{D80} $		2750 500 1350		nC nC nC
t <sub>d(on)</sub> t <sub>r</sub> t <sub>d(off)</sub> t <sub>f</sub>	$\begin{cases} V_{GS} = 10 \text{ V; } V_{DS} = 0.5 \bullet V_{DSS}; \\ I_{D} = I_{D80}; R_{G} = 1 \Omega \end{cases}$		210 500 900 350		ns ns ns ns
V <sub>F</sub>	(diode) $I_F = 300 \text{ A}; V_{GS} = 0 \text{ V}$		0.9	1.1	V
t <sub>rr</sub>	(diode) $I_F = 300 \text{ A}$ ; -di/dt = 500 A/µs; $V_{DS} = \frac{1}{2}$	V <sub>DSS</sub>	300		ns
R <sub>thJC</sub> R <sub>thJS</sub>	with heat transfer paste		0.07	0.05	K/W K/W

#### **Features**

- HiPerFET™ technology
  - low  $R_{\mbox{\scriptsize DSon}}$
  - dv/dt ruggedness
  - fast intrinsic reverse diode
- package
- low inductive current path
- screw connection to high current main terminals
- use of non interchangeable connectors for auxiliary terminals possible
- Kelvin source terminals for easy drive
- isolated ceramic base plate

## **Applications**

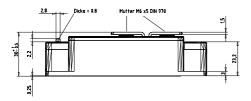
- converters with high power density for
  - main and auxiliary AC drives of electric vehicles
  - DC drives
  - power supplies

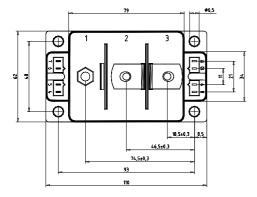


Module				
Symbol	Conditions	Maximum Ratings		
T <sub>VJ</sub>		-40+150 -40+125	°C	
V <sub>ISOL</sub>	I <sub>ISOL</sub> ≤ 1 mA; 50/60 Hz	3600	V~	
M <sub>d</sub>	Mounting torque (M6) Terminal connection torque (M6)	2.25 - 2.75 4.5 - 5.5	Nm Nm	

Symbol	Conditions	Ch	Characteristic Values	
		min.	typ.	max.
Weight			250	g

## **Dimensions in mm (1 mm = 0.0394")**





#### Optional accessories for modules

keyed twin plugs (UL758, style 1385, CSA class 5851, guide 460-1-1)

- Type ZY180L with wire length 350mm
   for pins 4 (yellow wire) and 5 (red wire)
- for pins 11 (yellow wire) and 10 (red wire)
- Type ZY180R with wire length 350mm
  - for pins 7 (yellow wire) and 6 (red wire)
  - for pins 8 (yellow wire) and 9 (red wire)